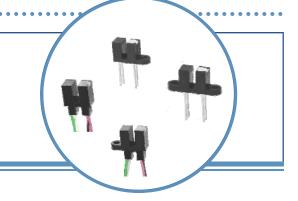


#### Features:

- 0.125" (3.175 mm) slot width
- Choice of aperture (0.050" or 0.010" width)
- Choice of opaque or IR transmissive shell material
- · Choice of mounting configurations
- · Choice of lead spacing or wires



## **Description:**

The slotted optical sensors in this series provide the flexibility of a custom device from a standard product line.

Building from a standard housing with a 0.125" (3.18mm) wide slot, the user can specify output logic state, output driver circuit, aperture width, aperture surface and mounting tab locations. Furthermore, an option of wire or PCB leads allows electrical interface flexibility.

The device body is an opaque plastic which minimizes sensitivity to both visible and near-infrared external light sources which may impact operation. Aperture width choices provide different optical resolution for motion sensing. A covered aperture provides dust protection, while an open aperture provides maximum protection against external light sources.

Phototransistor sensor devices are: OPB360, OPB370, OPB380, OPB390, OPB859, OPB860, OPB870, OPB880, OPB890. The OPB355 provides a photodiode detector, which has a lower linear output-versus-light.

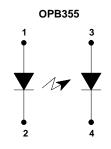
Wide electrical output current ranges are available. LED emissions are near-infrared (850-940nm).

Custom electrical, wire and cabling services are available.

Contact your local representative or OPTEK for more information. Compliant to EU RoHS Directive 2002/95/EC.

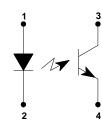
## **Applications:**

- · Non-contact object sensing
- · Assembly line automation
- Machine automation
- Equipment safety
- Machine safety



Wire	Colors
Color #	Description
1	Red
2	Black
3	White
4	Green

OPB360, OPB370, OPB380, OPB390 OPB859 OPB860, OPB870, OPB880, OPB890





**RoHS** 

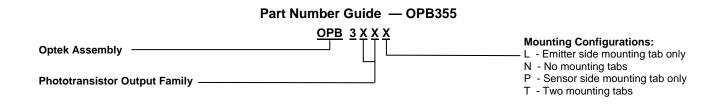
#### CONTAINS POLYSULFONE

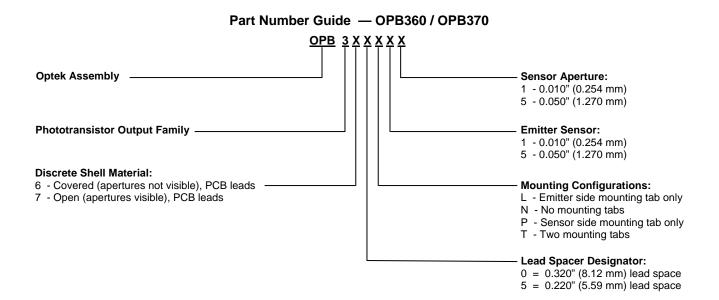
To avoid stress cracking, we suggest using ND Industries' Vibra-Tite for thread-locking.

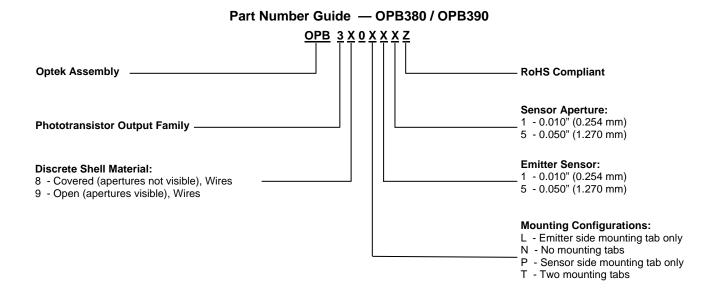
ND Vibra-Tite Formula 3 evaporates fast without causing structural failure in OPTEK's molded plastics.

Applies to: OPB360, OPB370, OPB380, OPB390 and OPB860, OPB870, OPB880, OPB890.

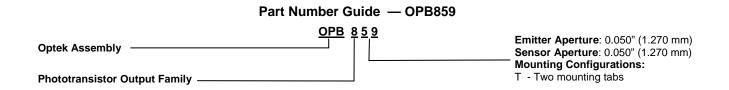


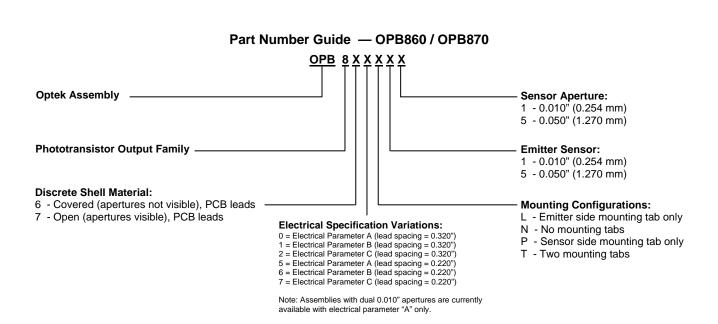


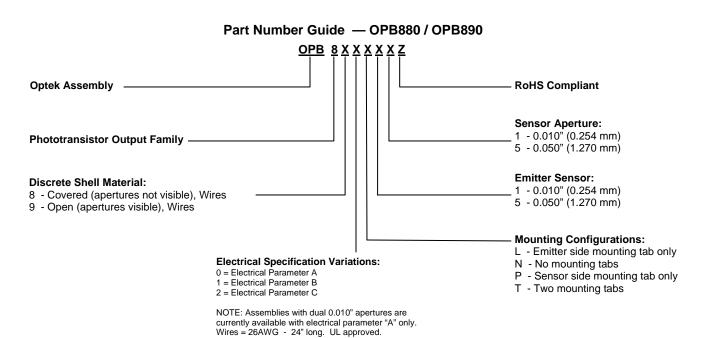






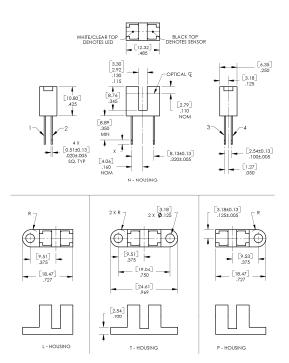




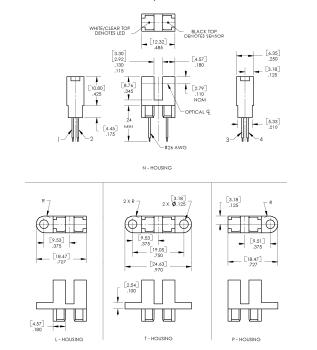




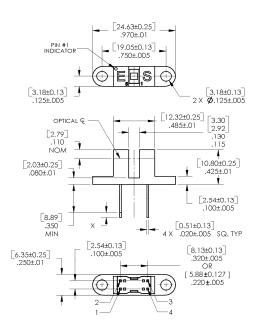
#### OPB355, OPB360, OPB370



## OPB380, OPB390

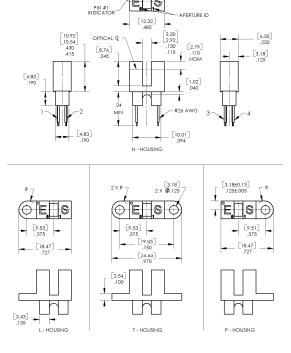


#### **OPB859**



Pin #	Emitter	Pin#	Transistor/Diode
1	Anode	3	Collector / Anode
2	Cathode	4	Emitter / Cathode

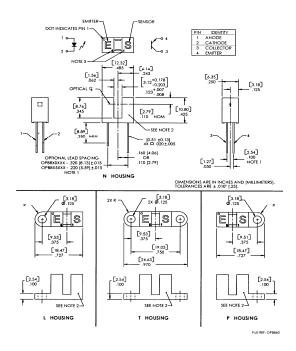
## OPB880, OPB890



DIMENSIONS ARE IN: [ MILLIMETERS] INCHES



## OPB860, OPB870





## **Absolute Maximum Ratings** (T<sub>A</sub>=25°C unless otherwise noted)

25dd Coldoning Formporaturo	200 0
Lead Soldering Temperature <sup>(7)</sup>	260° C
Operating Temperature <sup>(1) (2)</sup>	-40° C to +85° C
Storage Temperature <sup>(1) (2)</sup> OPB355, OPB360, OPB870, OPB859, OPB860, OPB870 Series OPB380, OPB390, OPB880, OPB890 Series	-40° C to +100° C -40° C to +85° C

#### Input LED

Forward DC Current OPB355, OPB360, OPB370, OPB380, OPB390, OPB859, OPB860, OPB870, OPB880, OPB890	50 mA
Peak Forward Current (1µs pulse width, 300 pps)	1 A
Reverse DC Voltage	2 V
Power Dissipation <sup>(2)</sup>	75 mW

## **Output Phototransistor/Diode**

Cathode-Anode Reverse Voltage -OPB355	60 V
Collector-Emitter Voltage OPB360, OPB370, OPB380, OPB390, OPB859, OPB860, OPB870, OPB880, OPB890 Series	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	30 mA
Power Dissipation <sup>(1)</sup>	100 mW

## Notes:

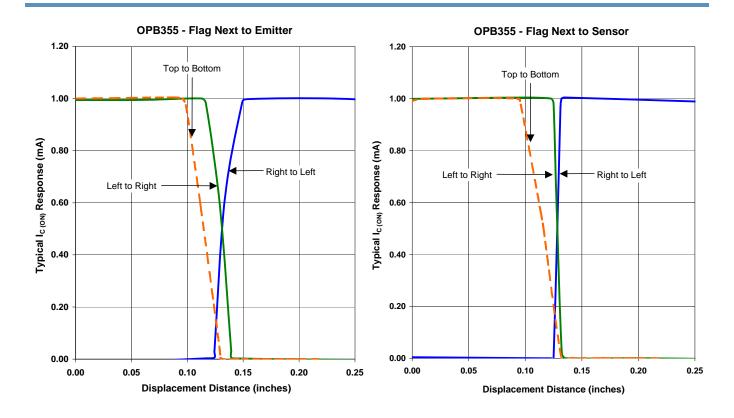
- (1) For wire series (OPB380, OPB390, OPB880 and OPB890), maximum storage and operating temperature is limited by the temperature rating of the lead wires.
- (2) Derate linearly 1.67 mW/° C above 25° C.
- (3) For OPB355, OPB360 and OPB370, polarity is denoted by color of housing top: LED (clear); sensor (black).
- (4) Cleaning agents methanol and isopropanol are recommended. Spray or wipe; do not submerge.
- (5) OPB380 and OPB390 wire terminations have 24" of 7-strand 26 AWG UL approved insulated wire on each terminal. These devices incorporate a wire strain relief at the housing surface. The insulation colors and functions are: IRED anode (red); IRED cathode (black); phototransistor collector (white); phototransistor emitter (green).
- (6) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (7) All parameters were tested using pulse technique.

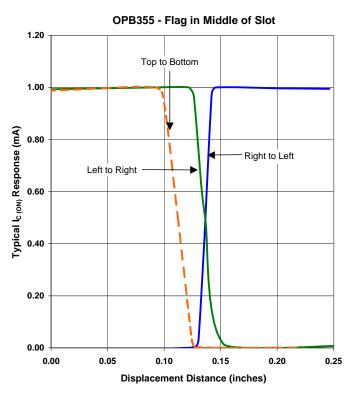


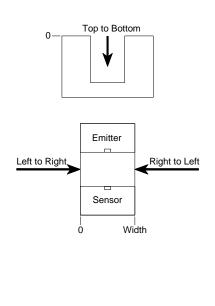
## **Electrical Characteristics** (T<sub>A</sub> = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Trans	istor/Diode (See OP240 for additional in	nformation	n—for re	eferenc	e only)	
V <sub>F</sub>	Forward Voltage	-	1.3	1.8	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	Reverse Current	-	-	100	μA	V <sub>R</sub> = 2 V
Output Dioc	le — OPB355 (See OPB950 for addition	al inform	ation —	for refe	erence or	ily)
$V_{BR}$	Reverse Diode Breakdown Voltage	60	-	-	V	$I_R = 100 \ \mu A, I_F = 0, E_E = 0$
$V_{FD}$	Forward Voltage Photodiode	-	-	1.2	V	$I_F = 1 \text{ mA}, I_F = 0, E_E = 0$
ID	Reverse Dark Current	-	-	60	nA	$V_R = 30 \text{ V}, E_E = 0, I_F = 0$
Output Tran	sistor (See OP550 for additional inform	ation—fo	r refere	nce only	y)	
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	I <sub>C</sub> = 1 mA
V <sub>(BR)ECO</sub>	Emitter-Collector Breakdown Voltage	5	-	-	V	Ι <sub>Ε</sub> = 100 μΑ
I <sub>CEO</sub>	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$
Coupled						
ΙL	On-State Collector Current OPB355 (L, N, P, T)	10	-	200	μa	V <sub>R</sub> = 5 V, I <sub>F</sub> = 40 mA
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage OPB859 OPB860/870/865/875 (Para. A) OPB861/871/866/876 (Para. B) OPB862/872/867/877 (Para. C) OPB880/890/ (Para. A) OPB881/891 (Para. B) OPB882/892 (Para. C)	- - - - -	- - - - -	0.4 0.4 0.4 0.6 0.4 0.4 0.6	V	$\begin{split} I_C &= 125~\mu\text{A},~I_F = 20~\text{mA} \\ I_C &= 400~\mu\text{A},~I_F = 20~\text{mA} \\ I_C &= 800~\mu\text{A},~I_F = 20~\text{mA} \\ I_C &= 1800~\mu\text{A},~I_F = 20~\text{mA} \\ I_C &= 400~\mu\text{A},~I_F = 20~\text{mA} \\ I_C &= 800~\mu\text{A},~I_F = 10~\text{mA} \\ I_C &= 1800~\mu\text{A},~I_F = 20~\text{mA} \end{split}$
	On-State Collector Current OPB36X, OPB37X (T, N, L, P 11) OPB36X, OPB37X (T, N, L, P 51) OPB36X, OPB37X (T, N, L, P 55) OPB38X, OPB39X (T, N, L, P 11) OPB38X, OPB39X (T, N, L, P 51) OPB38X, OPB39X (T, N, L, P 55)	1.0 2.5 3.5 1.0 2.5 3.5	- - - -	5 10 14 5 10	mA	$V_{CE} = 0.4 \text{ V}, I_F = 20 \text{ mA}$
$I_{C(ON)}$	OPB859	250	-	-	μA	$V_{CE} = 10 \text{ V}, I_F = 20 \text{ mA}$
	OPB860/870/865/875 (Para. A) OPB861/871/866/876 (Para. B) OPB862/872/867/877 (Para. C) OPB880/890/ (Para. A) OPB881/891 (Para. B) OPB882/892 (Para. C	0.5 1.0 1.8 0.5 1.0 1.8			mA	$\begin{split} &V_{CE} = 10 \text{ V}, \text{ I}_F = 20 \text{ mA} \\ &V_{CE} = 5 \text{ V}, \text{ I}_F = 10 \text{ mA} \\ &V_{CE} = 0.6 \text{ V}, \text{ I}_F = 20 \text{ mA} \\ &V_{CE} = 10 \text{ V}, \text{ I}_F = 20 \text{ mA} \\ &V_{CE} = 5 \text{ V}, \text{ I}_F = 10 \text{ mA} \\ &V_{CE} = 0.6 \text{ V}, \text{ I}_F = 20 \text{ mA} \end{split}$

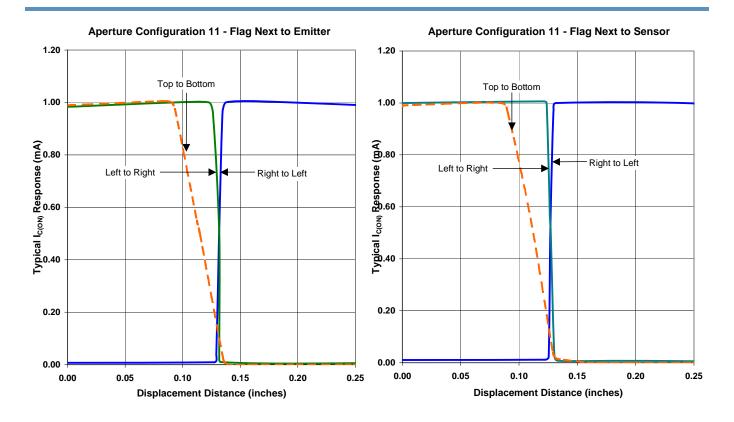




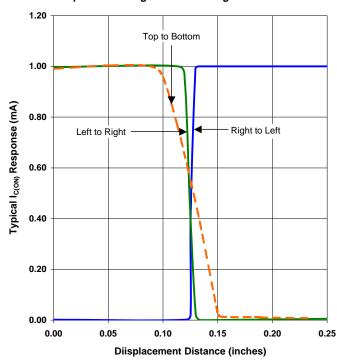


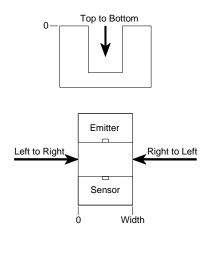




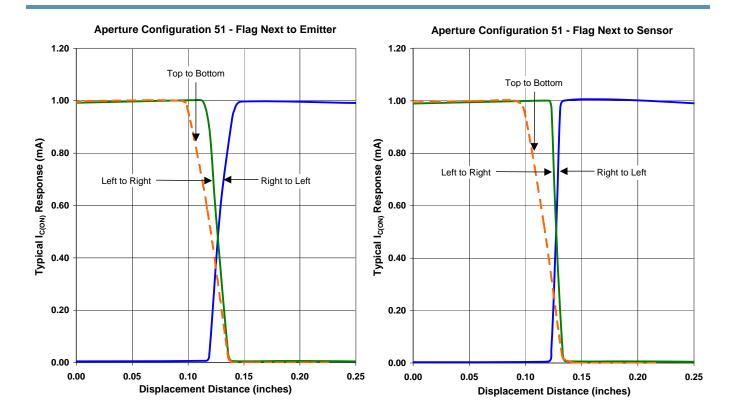


#### Aperture Configuration 11 - Flag in Middle of Slot

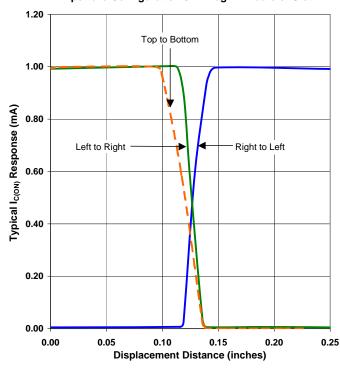


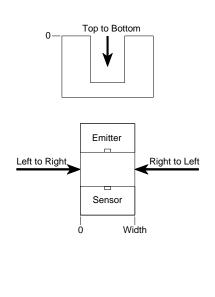




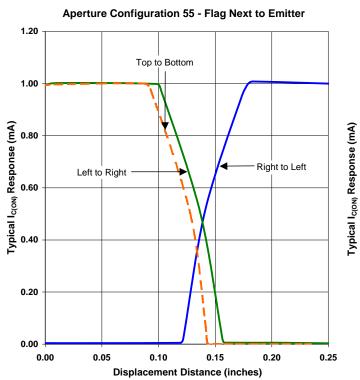


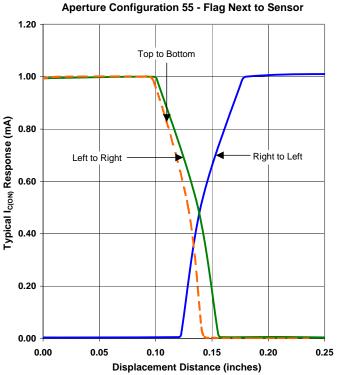
#### Aperture Configuration 51 - Flag in Middle of Slot











## Aperture Configuration 55 - Flag in Middle of Slot

